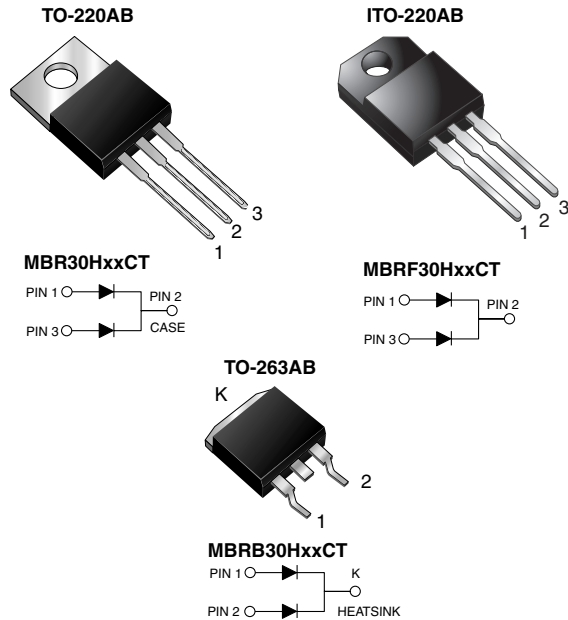




## Dual Common-Cathode Schottky Rectifier

High Barrier Technology for Improved High Temperature Performance



### FEATURES

- Guardring for overvoltage protection
- Lower power losses, high efficiency
- Low forward voltage drop
- Low leakage current
- High forward surge capability
- High frequency operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C (for TO-263AB package)
- Solder dip 260 °C, 40 s (for TO-220AB and ITO-220AB package)
- Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC



**RoHS**  
 COMPLIANT

### TYPICAL APPLICATIONS

For use in low voltage, high frequency rectifier of switching mode power supplies, freewheeling diodes, dc-to-dc converters or polarity protection application.

### MECHANICAL DATA

**Case:** TO-220AB, ITO-220AB, TO-263AB

Epoxy meets UL 94V-0 flammability rating

**Terminals:** Matte tin plated leads, solderable per J-STD-002 and JESD22-B102

E3 suffix for consumer grade, meets JESD 201 class 1A whisker test, HE3 suffix for high reliability grade (AEC-Q101 qualified), meets JESD 201 class 2 whisker test

**Polarity:** As marked

**Mounting Torque:** 10 in-lbs maximum

PRIMARY CHARACTERISTICS	
$I_{F(AV)}$	2 x 15 A
$V_{RRM}$	35 V to 60 V
$I_{FSM}$	150 A
$V_F$	0.56 V, 0.59 V
$I_R$	80 $\mu$ A, 60 $\mu$ A
$T_J$ max.	175 °C

MAXIMUM RATINGS ( $T_C = 25$ °C unless otherwise noted)						
PARAMETER	SYMBOL	MBR30H35CT	MBR30H45CT	MBR30H50CT	MBR30H60CT	UNIT
Maximum repetitive peak reverse voltage	$V_{RRM}$	35	45	50	60	V
Working peak reverse voltage	$V_{RWM}$	35	45	50	60	V
Maximum DC blocking voltage	$V_{DC}$	35	45	50	60	V
Max. average forward rectified current (Fig. 1)	$I_{F(AV)}$	total device per diode		30	15	A
Non-repetitive avalanche energy per diode at 25 °C, $I_{AS} = 4$ A, $L = 10$ mH	$E_{AS}$			80		mJ
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode	$I_{FSM}$			150		A
Peak repetitive reverse surge current per diode at $t_p = 2.0$ $\mu$ s, 1 kHz	$I_{RRM}$	1.0		0.5		A
Peak non-repetitive reverse energy (8/20 $\mu$ s waveform)	$E_{RSM}$	25		20		mJ

# New Product

## MBR(F,B)30H35CT thru MBR(F,B)30H60CT



Vishay General Semiconductor

MAXIMUM RATINGS (T <sub>C</sub> = 25 °C unless otherwise noted)						
PARAMETER	SYMBOL	MBR30H35CT	MBR30H45CT	MBR30H50CT	MBR30H60CT	UNIT
Electrostatic discharge capacitor voltage human body model: C = 100 pF, R = 1.5 kΩ	V <sub>C</sub>	25				kV
Voltage rate of change (rated V <sub>R</sub> )	dV/dt	10 000				V/μs
Operating junction temperature range	T <sub>J</sub>	- 65 to + 175				°C
Storage temperature range	T <sub>STG</sub>	- 65 to + 175				°C
Isolation voltage (ITO-220AB only) from terminal to heatsink t = 1 min	V <sub>AC</sub>	1500				V

ELECTRICAL CHARACTERISTICS (T <sub>C</sub> = 25 °C unless otherwise noted)								
PARAMETER	TEST CONDITIONS		SYMBOL	MBR30H35CT MBR30H45CT		MBR30H50CT MBR30H60CT		UNIT
				TYP.	MAX.	TYP.	MAX.	
Maximum instantaneous forward voltage per diode <sup>(1)</sup>	I <sub>F</sub> = 15 A	T <sub>J</sub> = 25 °C	V <sub>F</sub>	-	0.62	-	0.68	V
	I <sub>F</sub> = 15 A	T <sub>J</sub> = 125 °C		0.49	0.56	0.55	0.59	
	I <sub>F</sub> = 30 A	T <sub>J</sub> = 25 °C		-	0.73	-	0.83	
	I <sub>F</sub> = 30 A	T <sub>J</sub> = 125 °C		0.62	0.67	0.68	0.71	
Maximum reverse current at rated V <sub>R</sub> per diode <sup>(2)</sup>		T <sub>J</sub> = 25 °C T <sub>J</sub> = 125 °C	I <sub>R</sub>	- 5.0	80 15	- 4.0	60 15	μA mA

**Notes:**

- (1) Pulse test: 300 μs pulse width, 1 % duty cycle
- (2) Pulse test: Pulse width ≤ 40 ms

THERMAL CHARACTERISTICS (T <sub>C</sub> = 25 °C unless otherwise noted)					
PARAMETER	SYMBOL	MBR	MBRF	MBRB	UNIT
Thermal resistance, junction to case per diode	R <sub>θJC</sub>	1.5	4.5	1.5	°C/W

ORDERING INFORMATION					
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE
TO-220AB	MBR30H45CT-E3/45	1.85	45	50/tube	Tube
ITO-220AB	MBRF30H45CT-E3/45	1.99	45	50/tube	Tube
TO-263AB	MBRB30H45CT-E3/45	1.35	45	50/tube	Tube
TO-263AB	MBRB30H45CT-E3/81	1.35	81	800/teel	Tape and reel
TO-220AB	MBR30H45CTHE3/45 <sup>(1)</sup>	1.85	45	50/tube	Tube
ITO-220AB	MBRF30H45CTHE3/45 <sup>(1)</sup>	1.99	45	50/tube	Tube
TO-263AB	MBRB30H45CTHE3/45 <sup>(1)</sup>	1.35	45	50/tube	Tube
TO-263AB	MBRB30H45CTHE3/81 <sup>(1)</sup>	1.35	81	800/teel	Tape and reel

**Note:**

- (1) Automotive grade AEC-Q101 qualified



**RATINGS AND CHARACTERISTICS CURVES**

( $T_A = 25\text{ }^\circ\text{C}$  unless otherwise noted)

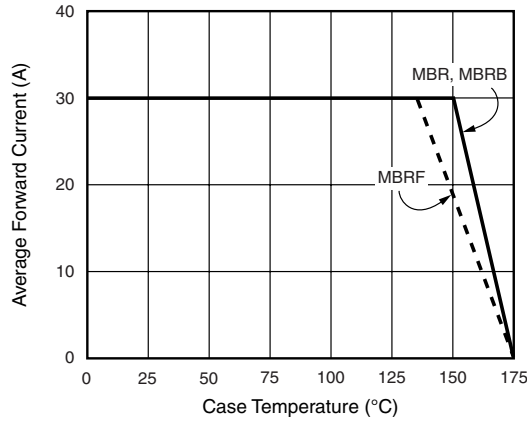


Figure 1. Forward Derating Curve

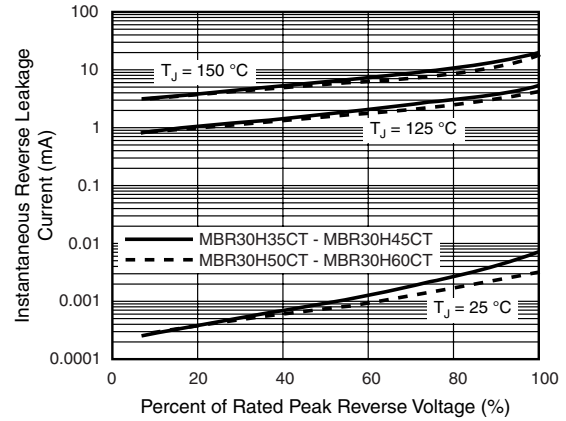


Figure 4. Typical Reverse Characteristics Per Diode

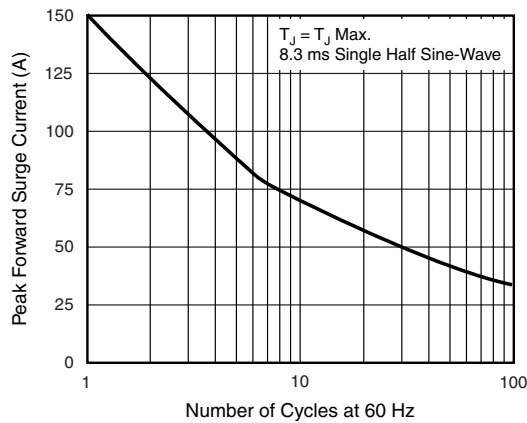


Figure 2. Maximum Non-Repetitive Peak Forward Surge Current Per Diode

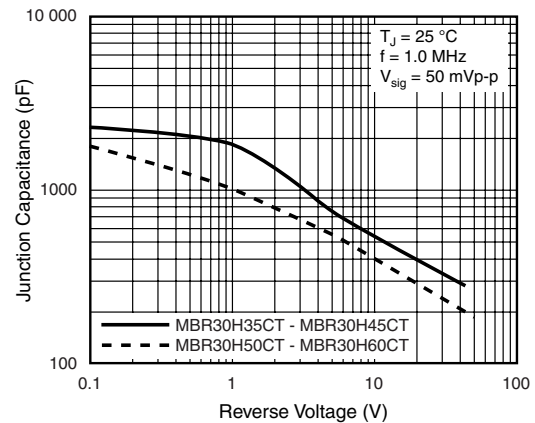


Figure 5. Typical Junction Capacitance Per Diode

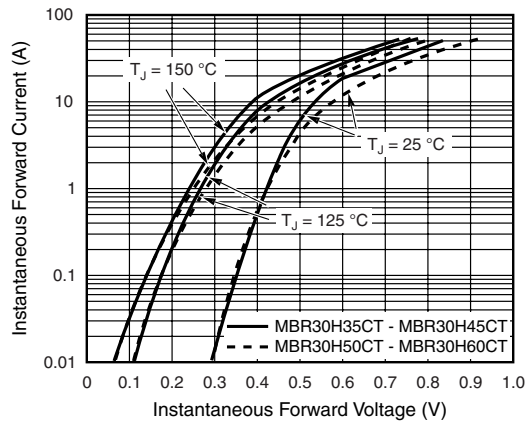


Figure 3. Typical Instantaneous Forward Characteristics Per Diode

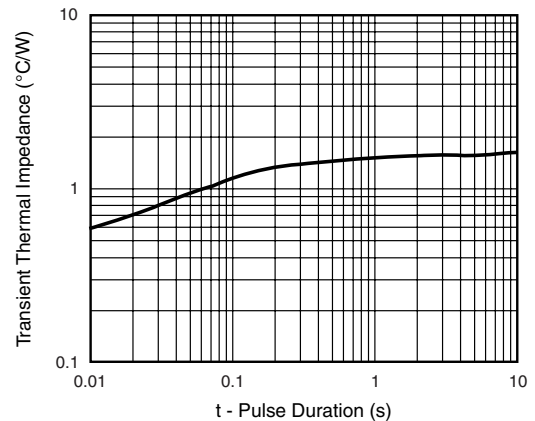


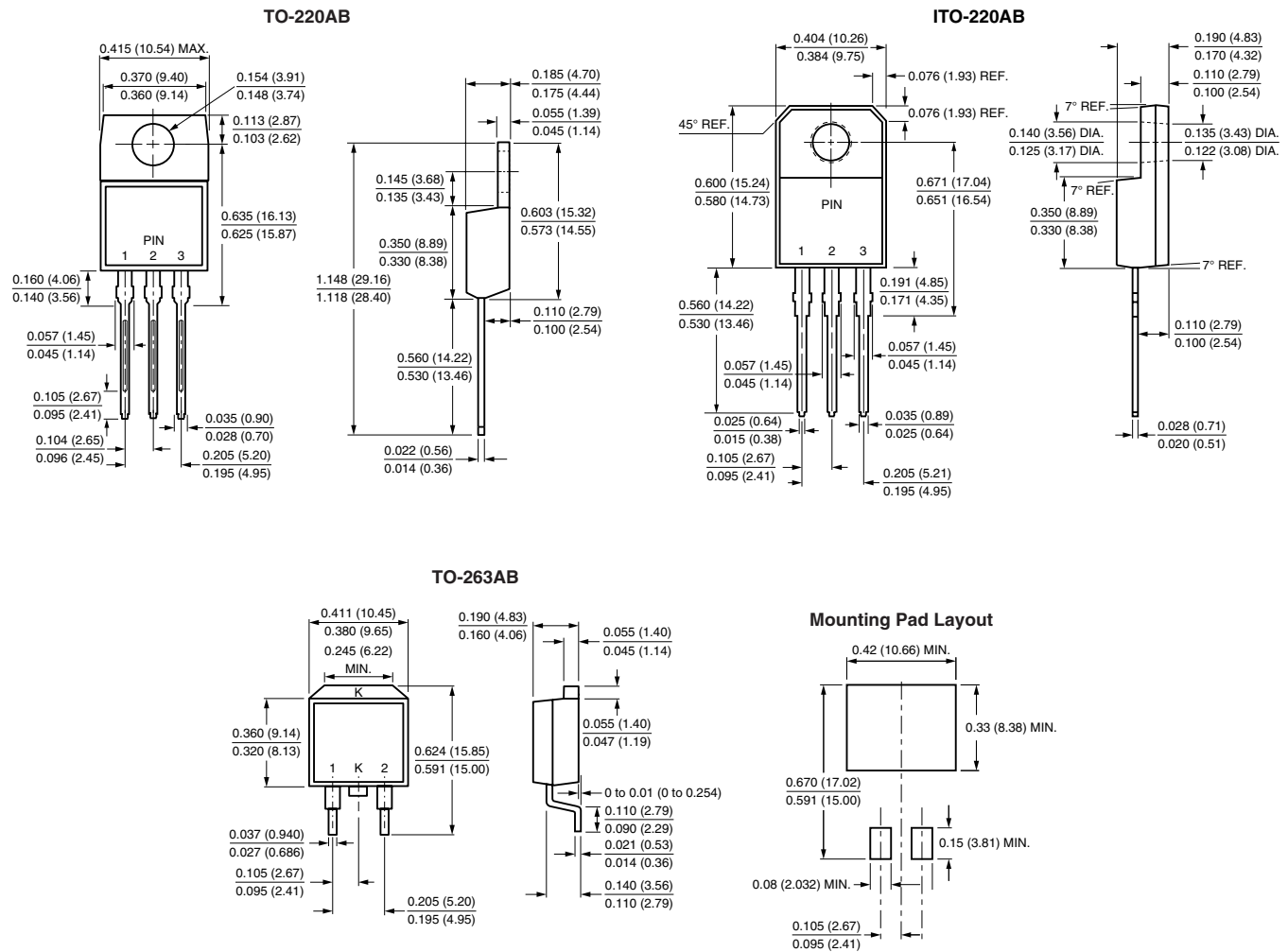
Figure 6. Typical Transient Thermal Impedance Per Diode

# New Product MBR(F,B)30H35CT thru MBR(F,B)30H60CT

Vishay General Semiconductor



## PACKAGE OUTLINE DIMENSIONS in inches (millimeters)





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